506866626 09/13/2021

### PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2 EPAS ID: PAT6913448

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

#### **CONVEYING PARTY DATA**

Name	Execution Date
ZVI OR-BACH	09/13/2021
BRIAN CRONQUIST	09/13/2021
DEEPAK SEKAR	09/13/2021

#### **RECEIVING PARTY DATA**

Name:	MONOLITHIC 3D INC.
Street Address:	1662 COVE POINT RD
City:	KLAMATH FALLS
State/Country:	OREGON
Postal Code:	97601

#### **PROPERTY NUMBERS Total: 1**

Property Type	Number
Application Number:	17473224

#### **CORRESPONDENCE DATA**

Fax Number:

Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.

**Phone:** 4088399533

Email: Brian@MonolithIC3D.com

Correspondent Name: BRIAN CRONQUIST
Address Line 1: 1662 COVE POINT RD

Address Line 4: KLAMATH FALLS, OREGON 97601

ATTORNEY DOCKET NUMBER: MONOLITHIC3D15HBVN_40LWC2		
NAME OF SUBMITTER:	BRIAN CRONQUIST	
SIGNATURE:	/Brian Cronquist/	
DATE SIGNED:	09/13/2021	

#### **Total Attachments: 3**

source=MonolithIC3D15HBVN\_40LWc2\_Assignment\_Zvi signed#page1.tif source=MonolithIC3D15HBVN\_40LWc2\_Assignment\_Brian signed#page1.tif source=MonolithIC3D15HBVN\_40LWc2\_Assignment\_Deepak signed#page1.tif

PATENT 50686626 REEL: 057465 FRAME: 0942

### **ASSIGNMENT**

Whereas, I, **Zvi Or-Bach** (hereinafter referred to as Assignor(s)), residing in Haifa, **Israel**; have made a certain invention, and executed United States Patent Application entitled:

# METHOD FOR PRODUCING A 3D SEMICONDUCTOR MEMORY DEVICE AND STRUCTURE

as described in U.S. Patent Application Serial No. 17/tbd and filed on or about September 13, 2021; and

Whereas, MonolithIC 3D™ Inc., a company located at 1662 Cove Point Road, Klamath Falls, OR 97601-9300 (hereinafter called "Assignee"), desires to acquire the entire right, title, and interest in the application and the invention, and to any applications, patents and/or utility model registrations filed or obtained therefor in every Country (hereinafter called the "Designated Countries").

Now therefore, for valuable consideration, receipt of which is hereby acknowledged,

I/we, the above named Assignor(s), hereby sell, assign and transfer to the above named Assignee the entire right, title and interest to file and/or obtain any applications, patents and/or utility model registrations in the Designated Countries as regards the United States application and the invention disclosed therein (including rights of priority based on the United States application), and I/we will execute without further consideration all papers deemed necessary by the Assignee in connection with such applications, patents and/or utility model registrations in the Designated Countries when called upon to do so by the Assignee.

Signed and Sealed:

INVENTOR:	pp-1/10/23				
<b>DATE</b> on <u>09 / 13 / 202</u> 1	(Zvi		Or-Bach)		
	First Name	Middle Initial	Last Name		

### ASSIGNMENT

Whereas, I, Brian Cronquist (hereinafter referred to as Assignor(s)), residing in Klamath Falls, Oregon; have made a certain invention, and United States Patent Application entitled:

## METHOD FOR PRODUCING A 3D SEMICONDUCTOR MEMORY DEVICE AND STRUCTURE

as described in U.S. Patent Application Serial No. 17/tbd and filed on or about September 13, 2021; and

Whereas, MonolithIC 3D™ Inc., a company located at 1662 Cove Point Road, Klamath Falls, OR 97601-9300 (hereinafter called "Assignee"), desires to acquire the entire right, title, and interest in the application and the invention, and to any applications, patents and/or utility model registrations filed or obtained therefor in every Country (hereinafter called the "Designated Countries").

Now therefore, for valuable consideration, receipt of which is hereby acknowledged,

I/we, the above named Assignor(s), hereby sell, assign and transfer to the above named Assignee the entire right, title and interest to file and/or obtain any applications, patents and/or utility model registrations in the Designated Countries as regards the United States application and the invention disclosed therein (including rights of priority based on the United States application), and I/we will execute without further consideration all papers deemed necessary by the Assignee in connection with such applications, patents and/or utility model registrations in the Designated Countries when called upon to do so by the Assignee.

Signed and Sealed:

INVENTOR:

DATE on

(Brian

First Name

Middle Initial

Cronquist)

Last Name

PATENT REEL: 057465 FRAME: 0944

### **ASSIGNMENT**

Whereas, I, Deepak Sekar (hereinafter referred to as Assignor(s)), residing in Sunnyvale, California; have made a certain invention, and United States Patent Application entitled:

# METHOD FOR PRODUCING A 3D SEMICONDUCTOR MEMORY DEVICE AND STRUCTURE

as described in U.S. Patent Application Serial No. 17/tbd and filed on or about September 13, 2021; and

Whereas, MonolithIC 3D™ Inc., a company located at 1662 Cove Point Road, Klamath Falls, OR 97601-9300 (hereinafter called "Assignee"), desires to acquire the entire right, title, and interest in the application and the invention, and to any applications, patents and/or utility model registrations filed or obtained therefor in every Country (hereinafter called the "Designated Countries").

Now therefore, for valuable consideration, receipt of which is hereby acknowledged,

I/we, the above named Assignor(s), hereby sell, assign and transfer to the above named Assignee the entire right, title and interest to file and/or obtain any applications, patents and/or utility model registrations in the Designated Countries as regards the United States application and the invention disclosed therein (including rights of priority based on the United States application), and I/we will execute without further consideration all papers deemed necessary by the Assignee in connection with such applications, patents and/or utility model registrations in the Designated Countries when called upon to do so by the Assignee.

Signed and Sealed:

IN	V	$\mathbf{E}$	N	<u> [(</u>	<u>)F</u>	<u> </u>

DATE on 09 / 13 / 2021

Day 1 c.sh

(**Deepak**First Name Middle Initial

Sekar)

Last Name

PATENT

DORIE:5259574665728401E;0945674b78377

RECORDED: 09/13/2021